National Semiconductor

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54LS112/DM54LS112A/DM74LS112A Dual Negative-Edge-Triggered Master-Slave J-K Flip-Flops with Preset, Clear, and Complementary Outputs

General Description

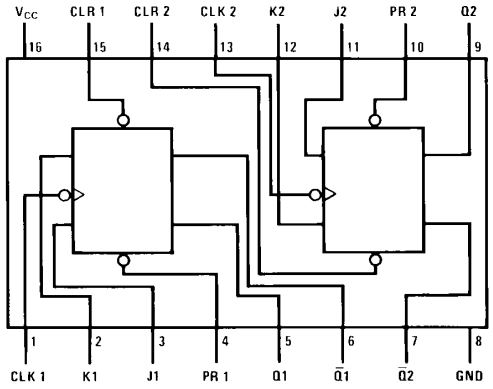
This device contains two independent negative-edge-triggered J-K flip-flops with complementary outputs. The J and K data is processed by the flip-flop on the falling edge of the clock pulse. The clock triggering occurs at a voltage level and is not directly related to the transition time of the falling edge of the clock pulse. Data on the J and K inputs may be changed while the clock is high or low without affecting the outputs as long as the setup and hold times are not violated. A low logic level on the preset or clear inputs will set or reset the outputs regardless of the logic levels of the other inputs.

Features

- Alternate Military/Aerospace device (54LS112) is available. Contact a National Semiconductor Sales Office/ Distributor for specifications.

Connection Diagram

Dual-In-Line Package



TL/F/6382–1

Order Number 54LS112DMQB, 54LS112FMQB, 54LS112LMQB, DM54LS112AJ, DM54LS112AW, DM74LS112AM or DM74LS112AN
See NS Package Number E20A, J16A, M16A, N16E or W16A

Function Table

Inputs					Outputs	
PR	CLR	CLK	J	K	Q	$\overline{Q}$
L	H	X	X	X	H	L
H	L	X	X	X	L	H
L	L	X	X	X	H*	H*
H	H	↓	L	L	Q_0	$\overline{Q}_0$
H	H	↓	H	L	H	L
H	H	↓	L	H	L	H
H	H	↓	H	H	Toggle	
H	H	H	X	X	Q_0	$\overline{Q}_0$

H = High Logic Level

L = Low Logic Level

X = Either Low or High Logic Level

↓ = Negative Going Edge of Pulse

* = This configuration is nonstable; that is, it will not persist when preset and/or clear inputs return to their inactive (high) level.

Q_0 = The output logic level before the indicated input conditions were established.

Toggle = Each output changes to the complement of its previous level on each falling edge of the clock pulse.

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RRD-B30M105/Printed in U. S. A.

Absolute Maximum Ratings (Note)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage	7V
Input Voltage	7V
Operating Free Air Temperature Range	
DM54LS and 54LS	−55°C to +125°C
DM74LS	0°C to +70°C
Storage Temperature Range	−65°C to +150°C

Note: *The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.*

Recommended Operating Conditions

Symbol	Parameter		DM54LS112A			DM74LS112A			Units
			Min	Nom	Max	Min	Nom	Max	
V_{CC}	Supply Voltage		4.5	5	5.5	4.75	5	5.25	V
V_{IH}	High Level Input Voltage		2			2			V
V_{IL}	Low Level Input Voltage				0.7			0.8	V
I_{OH}	High Level Output Current				−0.4			−0.4	mA
I_{OL}	Low Level Output Current				4			8	mA
f_{CLK}	Clock Frequency (Note 2)		0		30	0		30	MHz
f_{CLK}	Clock Frequency (Note 3)		0		25	0		25	MHz
t_W	Pulse Width (Note 2)	Clock High	20			20			ns
		Preset Low	25			25			
		Clear Low	25			25			
t_W	Pulse Width (Note 3)	Clock High	25			25			ns
		Preset Low	30			30			
		Clear Low	30			30			
t_{SU}	Setup Time (Notes 1 and 2)		20 ↓			20 ↓			ns
t_{SU}	Setup Time (Notes 1 and 3)		25 ↓			25 ↓			ns
t_H	Hold Time (Notes 1 and 2)		0 ↓			0 ↓			ns
t_H	Hold Time (Notes 1 and 3)		5 ↓			5 ↓			ns
T_A	Free Air Operating Temperature		−55		125	0		70	°C

Note 1: The symbol (↓) indicates the falling edge of the clock pulse is used for reference.

Note 2: $C_L = 15$ pF, $R_L = 2$ kΩ, $T_A = 25°C$ and $V_{CC} = 5V$.

Note 3: $C_L = 50$ pF, $R_L = 2$ kΩ, $T_A = 25°C$ and $V_{CC} = 5V$.

Electrical Characteristics over recommended operating free air temperature range (unless otherwise noted)

Symbol	Parameter	Conditions		Min	Typ (Note 1)	Max	Units
V_I	Input Clamp Voltage	$V_{CC} = Min$, $I_I = -18$ mA				−1.5	V
V_{OH}	High Level Output Voltage	$V_{CC} = Min$, $I_{OH} = Max$, $V_{IL} = Max$, $V_{IH} = Min$	DM54	2.5	3.4		V
			DM74	2.7	3.4		
V_{OL}	Low Level Output Voltage	$V_{CC} = Min$, $I_{OL} = Max$, $V_{IL} = Max$, $V_{IH} = Min$	DM54		0.25	0.4	V
			DM74		0.35	0.5	
		$I_{OL} = 4$ mA, $V_{CC} = Min$	DM74		0.25	0.4	
I_I	Input Current @ Max Input Voltage	$V_{CC} = Max$, $V_I = 7V$	J, K			0.1	mA
			Clear			0.3	
			Preset			0.3	
			Clock			0.4	

Electrical Characteristics

over recommended operating free air temperature range (unless otherwise noted) (Continued)

Symbol	Parameter	Conditions		Min	Typ (Note 1)	Max	Units
I_{IH}	High Level Input Current	V_{CC} = Max, V_I = 2.7V	J, K			20	μA
			Clear			60	
			Preset			60	
			Clock			80	
I_{IL}	Low Level Input Current	V_{CC} = Max, V_I = 0.4V	J, K			−0.4	mA
			Clear			−0.8	
			Preset			−0.8	
			Clock			−0.8	
I_{OS}	Short Circuit Output Current	V_{CC} = Max (Note 2)	DM54	−20		−100	mA
			DM74	−20		−100	
I_{CC}	Supply Current	V_{CC} = Max (Note 3)			4	6	mA

Switching Characteristics at V_{CC} = 5V and T_A = 25°C (See Section 1 for Test Waveforms and Output Load)

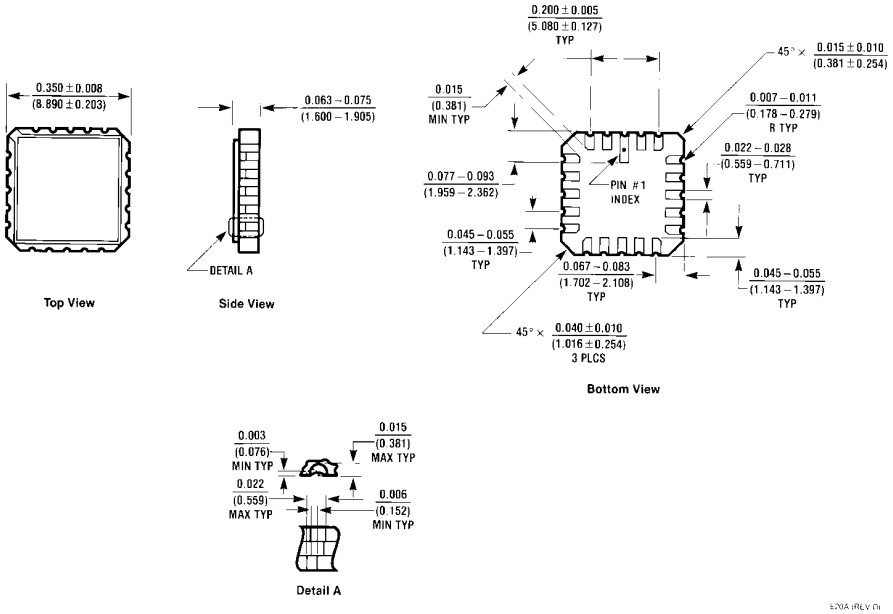
Symbol	Parameter	From (Input) To (Output)	R_L = 2 kΩ				Units
			C_L = 15 pF		C_L = 50 pF		
			Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency		30		25		MHz
t_{PLH}	Propagation Delay Time Low to High Level Output	Preset to Q		20		24	ns
t_{PHL}	Propagation Delay Time High to Low Level Output	Preset to $\overline{Q}$		20		28	ns
t_{PLH}	Propagation Delay Time Low to High Level Output	Clear to $\overline{Q}$		20		24	ns
t_{PHL}	Propagation Delay Time High to Low Level Output	Clear to Q		20		28	ns
t_{PLH}	Propagation Delay Time Low to High Level Output	Clock to Q or $\overline{Q}$		20		24	ns
t_{PHL}	Propagation Delay Time High to Low Level Output	Clock to Q or $\overline{Q}$		20		28	ns

Note 1: All typicals are at V_{CC} = 5V, T_A = 25°C.

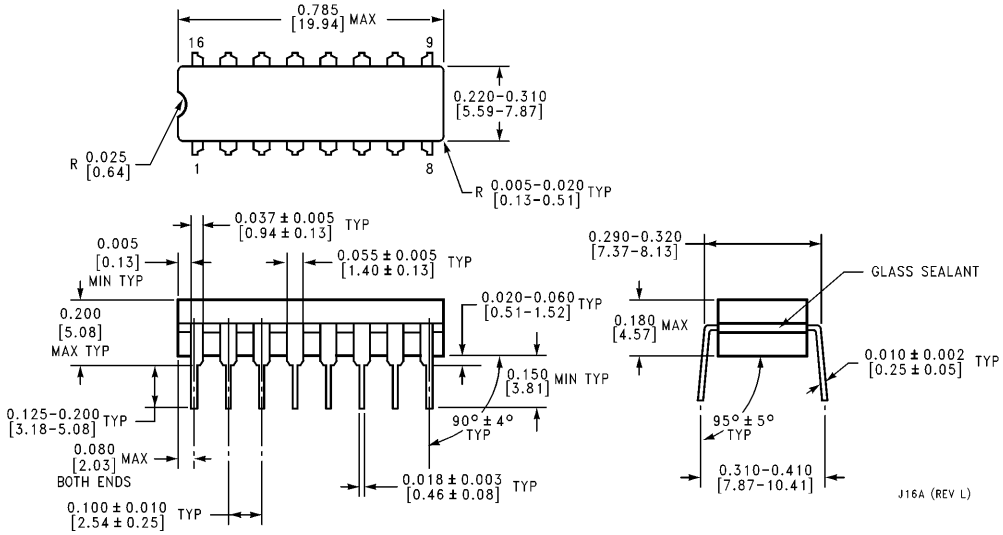
Note 2: Not more than one output should be shorted at a time, and the duration should not exceed one second. For devices, with feedback from the outputs, where shorting the outputs to ground may cause the outputs to change logic state an equivalent test may be performed where V_O = 2.25V and 2.125V for DM54 and DM74 series, respectively, with the minimum and maximum limits reduced by one half from their stated values. This is very useful when using automatic test equipment.

Note 3: With all outputs open, I_{CC} is measured with the Q and $\overline{Q}$ outputs high in turn. At the time of measurement the clock is grounded.

Physical Dimensions inches (millimeters)

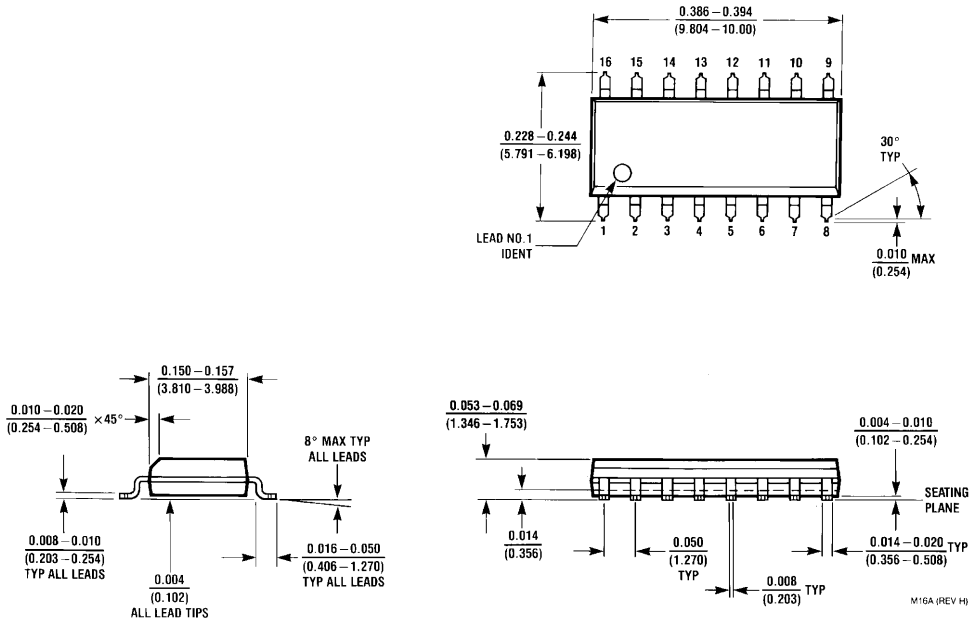


Ceramic Leadless Chip Carrier Package (E)
Order Number 54LS112LMQB
NS Package Number E20A

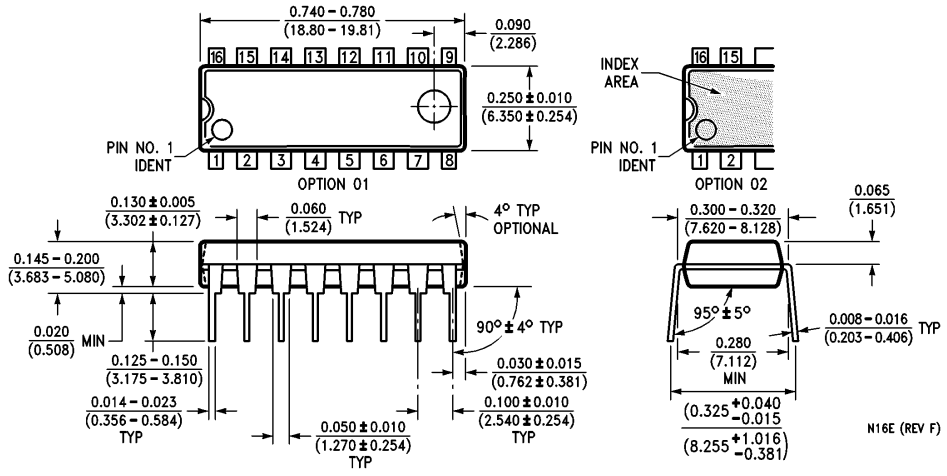


16-Lead Ceramic Dual-In-Line Package (J)
Order Number 54LS112DMQB or DM54LS112AJ
NS Package Number J16A

Physical Dimensions inches (millimeters) (Continued)

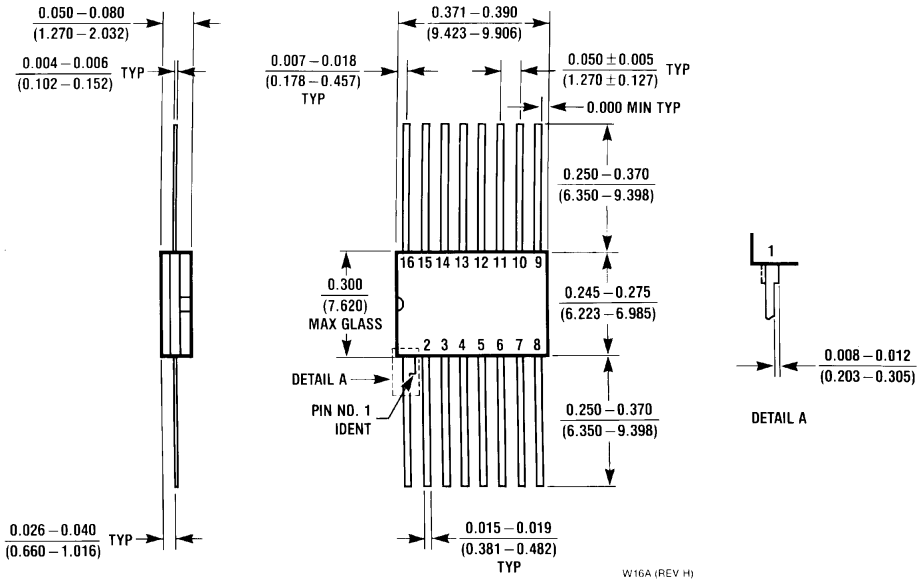


16-Lead Small Outline Molded Package (M)
Order Number DM74LS112AM
NS Package Number M16A



16-Lead Molded Dual-In-Line Package (N)
Order Number DM74LS112AN
NS Package Number N16E

Physical Dimensions inches (millimeters) (Continued)



16-Lead Ceramic Flat Package (W)
Order Number 54LS112FMQB or DM54LS112AW
NS Package Number W16A

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